NSN 5961-00-618-4854

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-618-4854 **Inclosure Material:** Glass **Overall Length:** 0.600 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.265 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 145.0 reverse breakdown voltage, dc and 103.0 reverse voltage, total rms **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Leads silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0